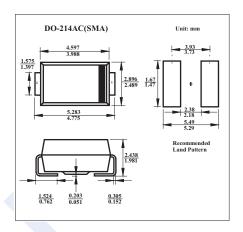
SMD Type Diodes

Surface Mount Schottky Barrier Rectifiier KCD32 THRU KCD310

(SCD32 THRU SCD310)

Features

- For surface mounted applications.
- Low profile package.
- Built-in strain relief.
- Metal silicon junction, majority carrier conduction.
- Low power loss, high efficiency.
- High current capability, low forward voltage drop.
- High surge capability.



■ Absolute Maximum Ratings and Electrical Characteristics at 25°C

Parameter	Symbol	KCD32	KCD34	KCD36	KCD310	Unit
Maximum repetitive peak reverse voltage	VRRM	20	40	60	100	V
Maximum RMS voltage	VRMS	14	28	42	70	V
Maximum DC blocking voltage	VDC	20	40	60	100	V
Maximum average forward rectified current	I(AV)	3				Α
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	80				А
Maximum instantaneous forward voltage at 3.0A * 1	VF	0.5 0.7		0.85	V	
Maximum DC reverse current * 1 Ta=25℃ at rated DC blocking voltage Ta=100℃	lr	0.5				mA
		2	0	10		IIIA
Typical thermal resistance	R θ JA R θ JL	55 17				°C/W
Operating junction temperature range	TJ	-55 to +125 -55 to +150		$^{\circ}$		
Storage temperature range	Tstg	-55 to +150				°C

^{* 1.} Pulse test: 300ms pulse width, 1% duty cycle.